TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process) (Darlington)

## 2SD1224

Pulse Motor Drive, Hammer Drive Applications

**Switching Applications** 

**Power Amplifier Applications** 

• High DC current gain:  $h_{FE} = 4000$  (min) ( $V_{CE} = 2$  V,  $I_{C} = 150$  mA)

• Low saturation voltage:  $V_{CE (sat)} = 1.5 \text{ V (max) (IC} = 1 \text{ A, IB} = 1 \text{ mA})$ 

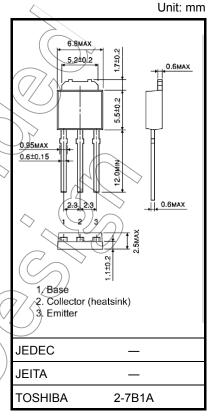
## **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	30	$(\checkmark \checkmark)$	
Collector-emitter voltage		V <sub>CEO</sub>	30	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	
Emitter-base voltage		V <sub>EBO</sub>	10	×	
Collector current		IC	1.5		
Base current		ΙΒ	0.15	Α	
Collector power dissipation	Ta = 25°C	P <sub>C</sub> ^	1.0	W_	
	Tc = 25°C	FC (	10		
Junction temperature		Tj	150	\cdot\cdot\cdot\	
Storage temperature range		T <sub>stg</sub>	) -55 to 150	°C	

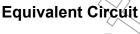
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

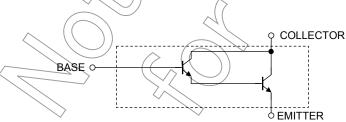
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



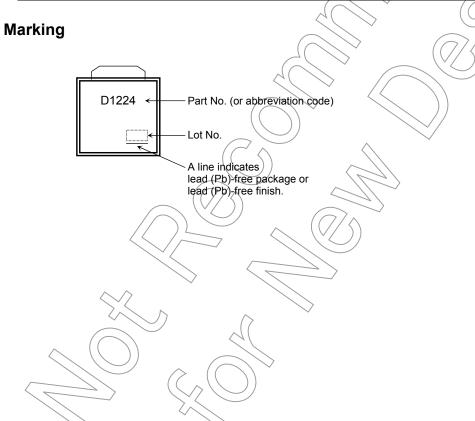
Weight: 0.36 g (typ.)



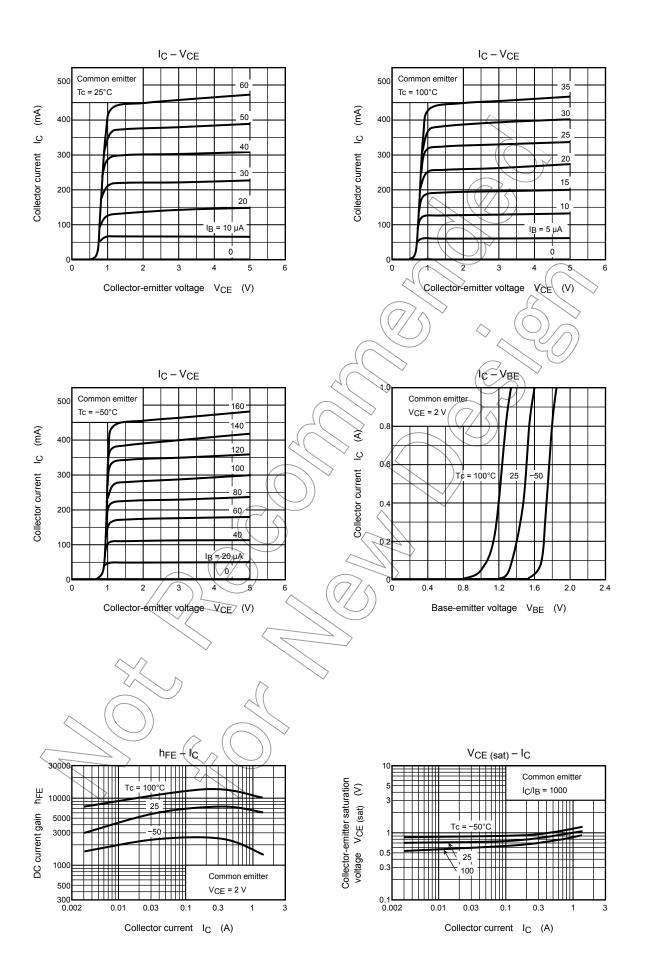


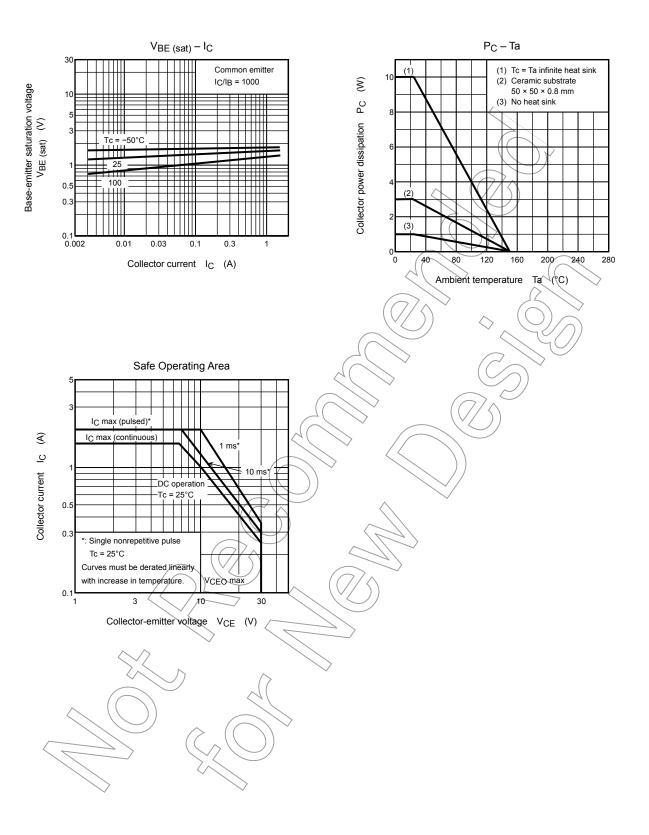
## Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0	_	_	10	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 10 V, I <sub>C</sub> = 0	_	_	10	μΑ
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	30	_	_	V
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 150 mA	4000	_	_	
Collector-emitter	saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 1 mA	(F	) / _	1.5	V
Base-emitter satu	ıration voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 1 mA	$\nearrow$	_	2.2	V
Switching time  Storage time  Fall time	t <sub>on</sub>	OUTPUT 20 μs I <sub>B1</sub>	<u>)</u>	0.18	_		
	Storage time	t <sub>stg</sub>	INPUTO WIND INPUTO INPU	-	0.6	<u>\</u>	μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = -I <sub>B2</sub> = 1 mA, DUTY CYCLE ≥ 1%		0.3	) –	



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